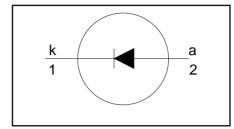
PBYR1645F, **PBYR1645X**

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

$$V_R = 40 \text{ V} / 45 \text{ V}$$
 $I_{F(AV)} = 16 \text{ A}$
 $V_F \le 0.6 \text{ V}$

GENERAL DESCRIPTION

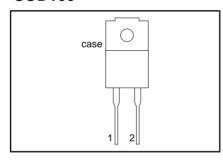
Schottky rectifier diodes in a plastic envelope with electrically isolated mounting tab. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR1645F is supplied in the SOD100 package. The PBYR1645X is supplied in the SOD113 package.

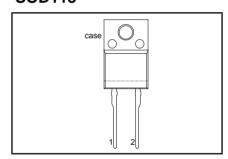
PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	isolated		

SOD100



SOD113



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	RAMETER CONDITIONS		MA	AX.	UNIT
V	Dook ropotitivo rovorgo	PBYR16 PBYR16		40F 40X	45F 45X	V
V_{RRM}	Peak repetitive reverse voltage		-	40	45	V
V_{RWM}	Working peak reverse voltage		-	40	45	V
V_R	Continuous reverse voltage	T _{hs} ≤ 97 °C	-	40	45	V
I _{F(AV)}	Average rectified forward current	square wave; δ = 0.5; $T_{hs} \le 95$ °C	-	1	6	Α
I _{FRM}	Repetitive peak forward current	square wave; $\delta = 0.5$; $T_{hs} \le 95$ °C	-	3	2	А
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; $T_j = 125 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{\text{RRM(max)}}$	-		20 32	A A
I _{RRM}	Peak repetitive reverse surge current	pulse width and repetition rate limited by T _{i max}	-	•	1	Α
T _j	Operating junction temperature	, max	-	15	50	°C
T_{stg}	Storage temperature		- 65	17	75	°C

PBYR1645F, PBYR1645X

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Peak isolation voltage from both terminals to external heatsink	SOD100 package; R.H. ≤ 65%; clean and dustfree	ı	1	1500	V
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	SOD113 package; f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-	-	2500	V
C _{isol}	Capacitance from pin 1 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.2	K/W
R _{th i-a}	1	in free air	-	55	-	K/W

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage	$I_F = 16 \text{ A}; T_i = 125^{\circ}\text{C}$	-	0.53	0.6	٧
		$I_{\rm F} = 16 {\rm A}$	-	0.55	0.68	V
I _R	Reverse current	$\dot{V}_R = V_{RWM}$	-	0.2	1.7	mΑ
		$V_R = V_{RWM}$; $T_j = 100^{\circ}C$	-	27	40	mΑ
C_d	Junction capacitance	$V_R = 5 \hat{V}$; $f = 1 MHz$, $T_j = 25 \hat{C}$ to 125 \hat{C}	-	470	-	pF

PBYR1645F, PBYR1645X

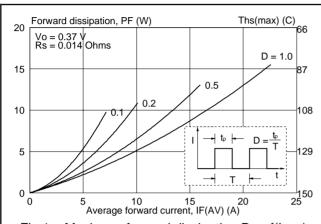


Fig.1. Maximum forward dissipation $P_F = f(I_{F(AV)})$; square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.

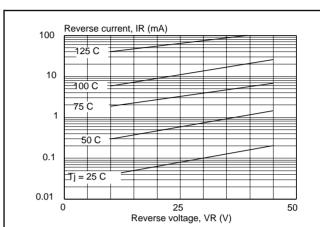


Fig.4. Typical reverse leakage current; $I_R = f(V_R)$; parameter T_i

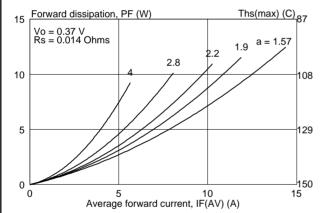
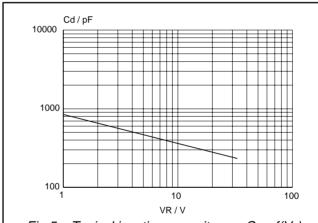


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = f(AV) $factor = I_{F(RMS)} / I_{F(AV)}$.



Typical junction capacitance; $C_d = f(V_R)$; f = 1 MHz; $T_j = 25^{\circ}\text{C}$ to 125°C .

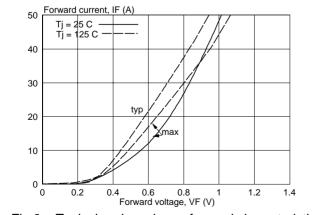
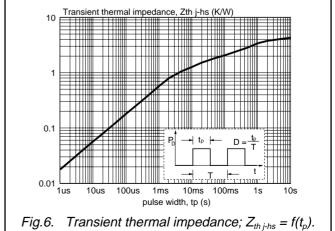
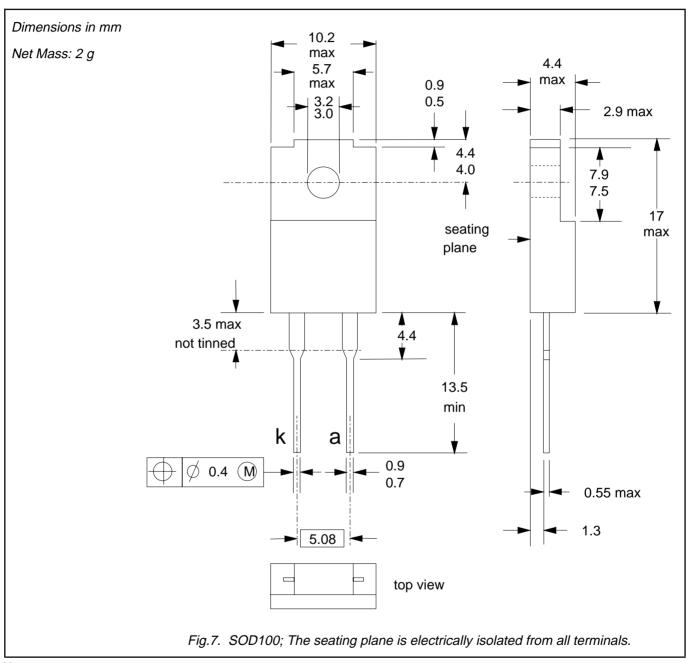


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i



PBYR1645F, PBYR1645X

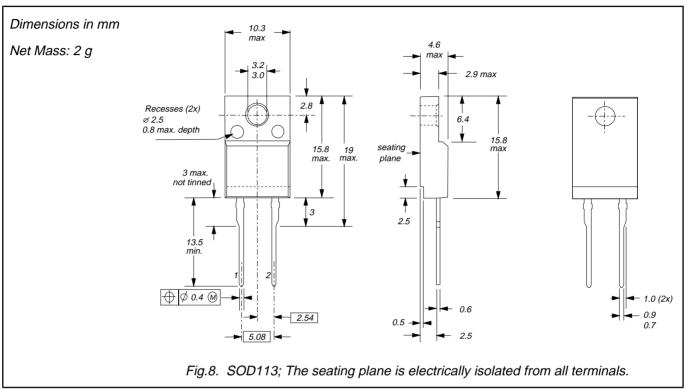
MECHANICAL DATA



- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

PBYR1645F, PBYR1645X

MECHANICAL DATA



Notes

- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Rectifier diodes Schottky barrier

PBYR1645F, PBYR1645X

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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